Datasheet

HSPR-X-I-2G-IN

Ultra High-Speed Photoreceiver with InGaAs-PIN Photodiode



The picture shows the HSPR-X-I-2G-IN-FS with free space input. The photoreceiver will be delivered without post holder and post.

Features	Bandwidth 10 kHz 2 GHz InGaAs-PIN detector Spectral range 900 1700 nm Amplifier transimpedance (gain) 5 x 10 ³ V/A (inverting) Conversion gain 4.75 x 10 ³ V/W @ 1550 nm Spectroscopy Ultra-fast pulse and transient measurements Optical triggering Optical front-end for oscilloscopes and ultra-fast A/D converters			
Applications				
Specifications	Test conditions	$V_{s} = +15 \text{ V}, T_{A} =$	25 °C, system impedance = 50 Ω	
Gain	Amplifier transimpedance Conversion gain	5 x 10 ³ V/A 4.75 x 10 ³ V/W	(@ 50 Ω load, inverting) (typ. @ 1550 nm)	
Frequency Response	Lower cut-off frequency (-3 dB) Upper cut-off frequency (-3 dB) Rise/fall time (10 % - 90 %)	10 kHz 2 GHz 180 ps	(±25 %) (±15 %) (±15 %)	
Input/Detector	Detector material Active area	InGaAs-PIN photo FS-version: FC-version:	odiode Ø 100 μm integrated ball lens, suitable for fibers up to 62.5 μm core diameter	
	Spectral range Max. optical peak input power	900 1700 nm 210 µW AC 10 mW CW	(for linear amplification, @ 1550 nm) (to prevent saturation, @ 1550 nm)	
Noise	NEP	11 pW/√Hz	(@ 1550 nm, 100 MHz)	

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

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Specifications (continued)			
Output	Output impedance Output VSWR Output return loss Max. output voltage Output noise * The peak-to-peak output no	50 Ω (designed for 50 Ω load) 1.4: 1 (@ f < 2.5 GHz) 15.5 dB (@ f < 2.5 GHz) 2.0 V_{PP} (@ 50 Ω load, for linear amplification) typ. 2.5 m V_{RMS} or 17 m V_{PP} * (measurement BW: 4 GHz) bise is derived from the RMS noise as follows: $V_{PP} = V_{RMS}$ x 6.6	
	(99.9% of the time the output noise voltage will be within the specified peak-to-peak value.)		
Power Supply	Supply voltage	+15 V, 150 mA typ. (depends on operating conditions, recommended power supply capability minimum 200 mA)	
Case	Weight Material	100 g (0.23 lbs) AlMg4.5Mn, nickel-plated	
Temperature Range	Storage temperature Operating temperature	−40 +100 °C 0 +60 °C	
Absolute Maximum Ratings	Power supply voltage Optical input power	±18.5 V 12 mW (averaged)	
Spectral Response	1.0 0.9 0.8 0.7 0.6 A/W 0.5 0.4 0.3 0.2 0.1 0 800 900 1000	Photo sensitivity 1100 1200 1300 1400 1500 1600 1700 1800 Wavelength - nm	
Connectors	Input Output Power supply	HSPR-X-I-2G-IN-FS 25 mm round flange for free space applications HSPR-X-I-2G-IN-FC FC fiber optic receptacle SMA jack (female) Lemo® series 1S, 3-pin fixed socket (mating plug type: FFA.1S.303.CLAC52) Pin 1: +15 V Pin 2: NC Pin 3: GND PIN 2 PIN 3 GND	

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HSPR-X-I-2G-IN-FS Available Models free space input HSPR-X-I-2G-IN-FC fiber optic receptacle HSPR-X-S customized versions available on request **Dimensions** HSPR-X-I-2G-IN-FS HSPR-X-I-2G-IN-FC OPTICAL IN OPTICAL IN OUT POWER POWER 25.0 54.0 15.5 2.1 mm distance to active area All measures in mm unless otherwise noted.

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